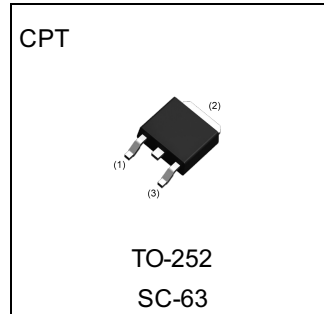


| Parameter | Value |
|-----------|-------|
| V_{CEO} | 80V |
| I_C | 1A |

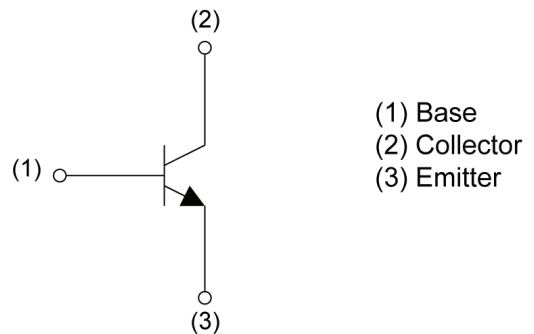
●Outline



●Features

- 1)High V_{CEO} , $V_{CEO}=80V$
- 2)High I_C , $I_C=1A(DC)$
- 3)Good h_{FE} linearity
- 4)Low $V_{CE(sat)}$
- 5)Complements the 2SB1181

●Inner circuit



- (1) Base
- (2) Collector
- (3) Emitter

●Application

Low frequency power amplifier

●Packaging specifications

| Part No. | Package | Package size | Taping code | Reel size (mm) | Tape width (mm) | Basic ordering unit.(pcs) | Marking |
|----------|---------|--------------|-------------|----------------|-----------------|---------------------------|---------|
| 2SD1733 | CPT | 6595 | TL | 330 | 16 | 2500 | D1733 |

● Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Values | Unit |
|------------------------------|------------|-------------|------------------|
| Collector-base voltage | V_{CBO} | 120 | V |
| Collector-emitter voltage | V_{CEO} | 80 | V |
| Emitter-base voltage | V_{EBO} | 5 | V |
| Collector current | I_C | 1 | A |
| Power dissipation | P_D^{*1} | 1 | W |
| | P_D^{*2} | 10 | W |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Range of storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

● Electrical characteristics ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Conditions | Values | | | Unit |
|--------------------------------------|---------------|--|--------|------|------|---------------|
| | | | Min. | Typ. | Max. | |
| Collector-base breakdown voltage | BV_{CBO} | $I_C = 50\mu\text{A}$ | 120 | - | - | V |
| Collector-emitter breakdown voltage | BV_{CEO} | $I_C = 1\text{mA}$ | 80 | - | - | V |
| Emitter-base breakdown voltage | BV_{EBO} | $I_E = 50\mu\text{A}$ | 5 | - | - | V |
| Collector cut-off current | I_{CBO} | $V_{CB} = 100\text{V}$ | - | - | 1.0 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB} = 4\text{V}$ | - | - | 1.0 | μA |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 500\text{mA}, I_B = 20\text{mA}$ | - | - | 400 | mV |
| DC current gain | h_{FE} | $V_{CE} = 3\text{V}, I_C = 500\text{mA}$ | 82 | - | 390 | - |
| Transition frequency | f_T | $V_{CE} = 10\text{V}, I_E = -50\text{mA}, f = 100\text{MHz}$ | - | 100 | - | MHz |
| Output capacitance | C_{ob} | $V_{CB} = 10\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$ | - | 20 | - | pF |

h_{FE} values are classified as follows :

| rank | P | Q | R | - | - |
|----------|--------|---------|---------|---|---|
| h_{FE} | 82-180 | 120-270 | 180-390 | - | - |

*1 $T_a = 25^\circ\text{C}$

*2 $T_c = 25^\circ\text{C}$

● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.1 Ground Emitter Propagation Characteristics

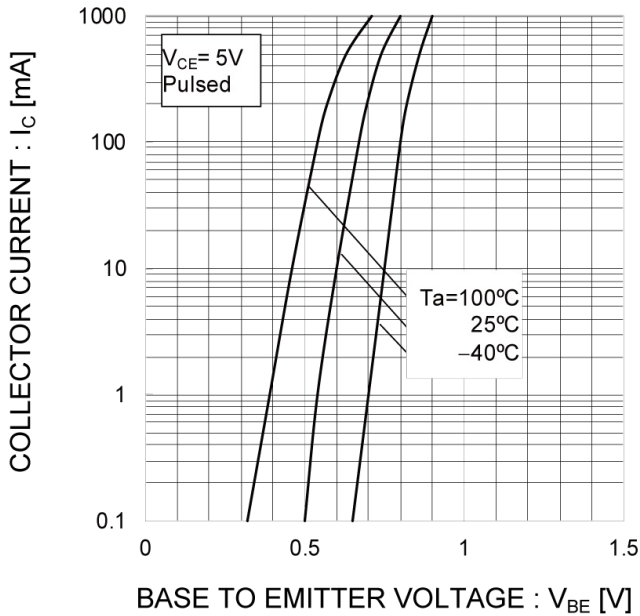


Fig.2 Typical Output Characteristics

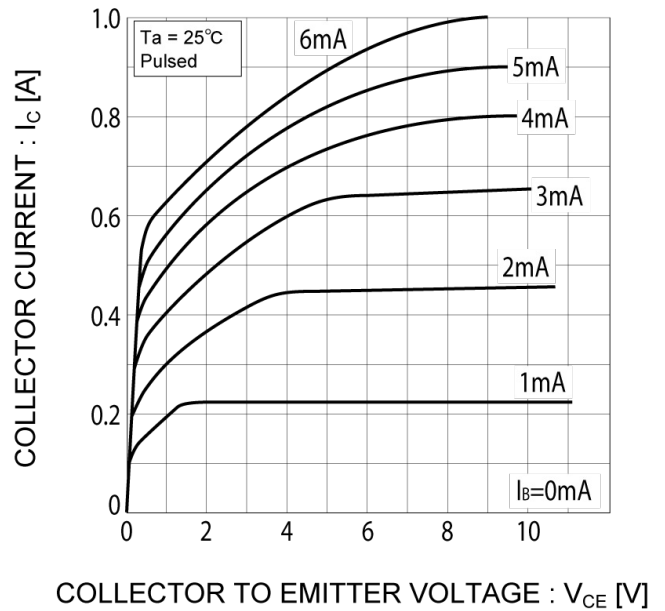


Fig.3 DC Current Gain vs. Collector Current (I)

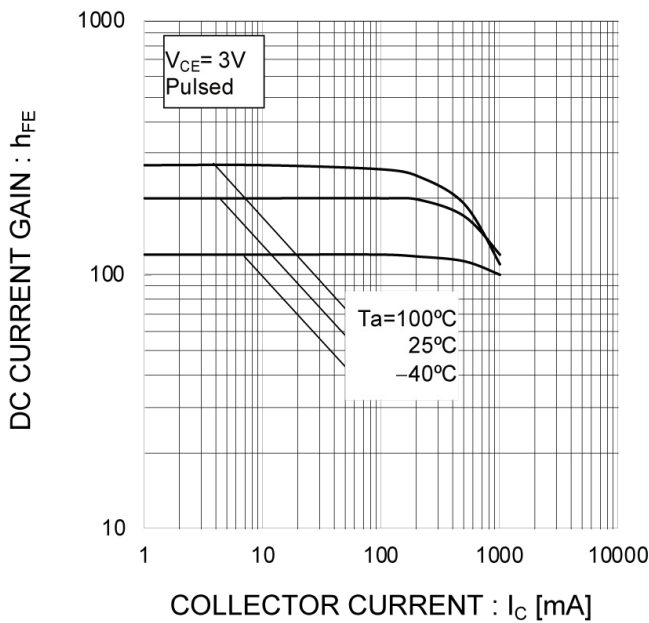
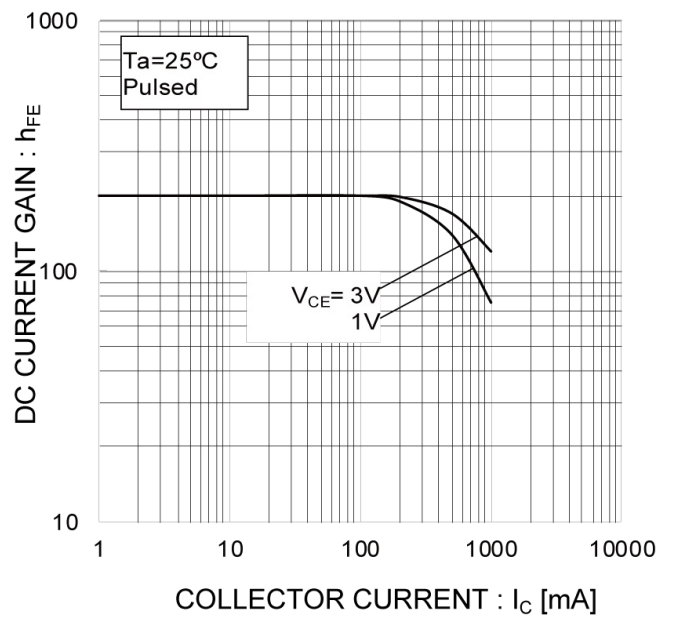


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

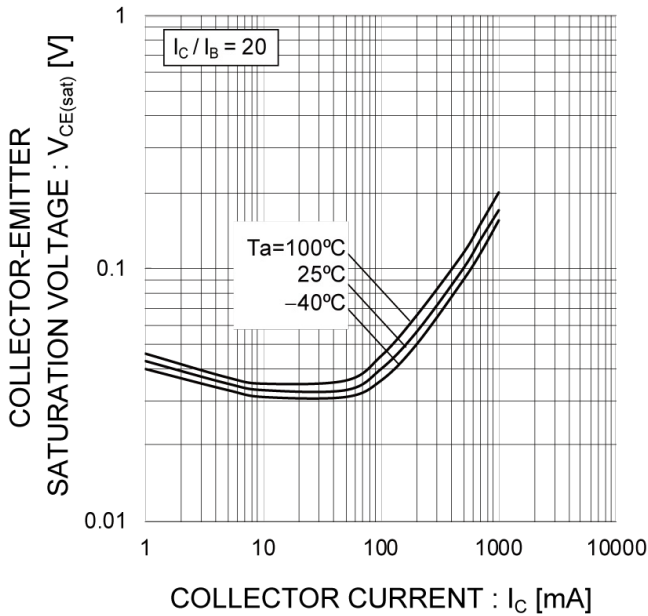


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

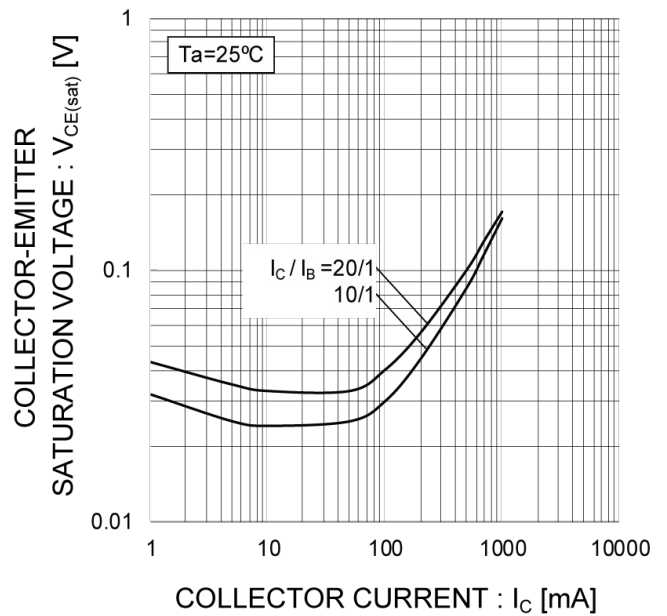


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

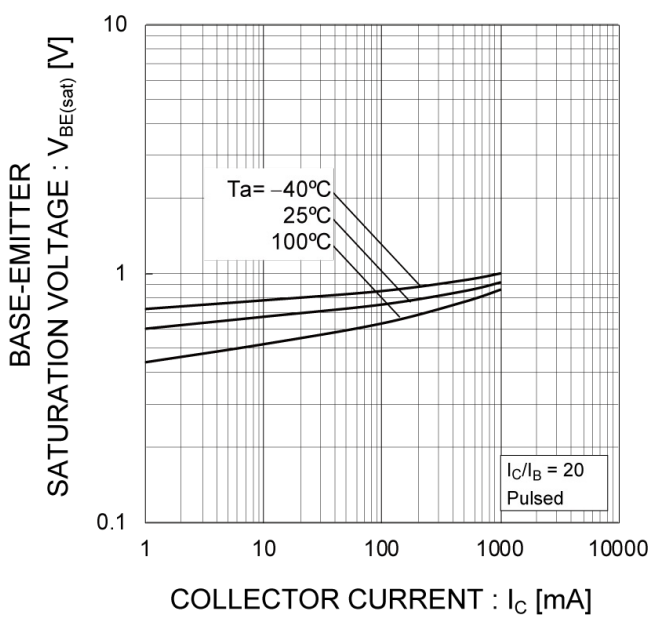
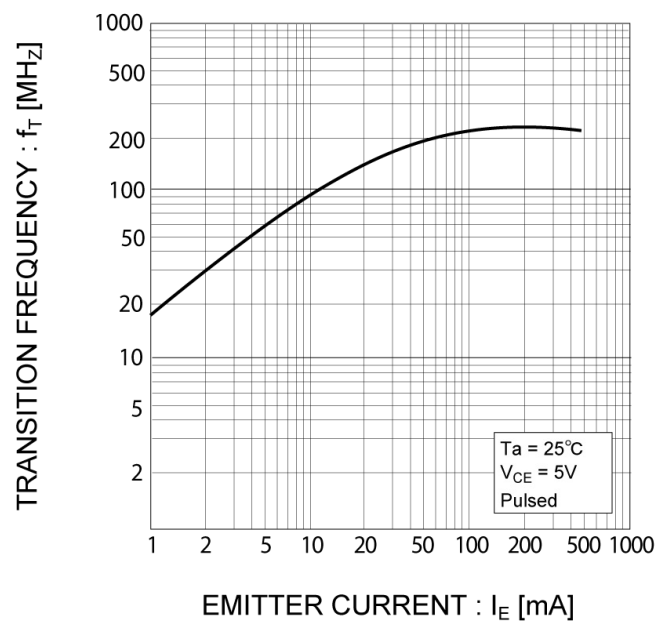


Fig.8 Gain Bandwidth Product vs. Emitter Current



●Electrical characteristic curves($T_a = 25^\circ\text{C}$)

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage
Collector output capacitance vs. Collector-Base Voltage

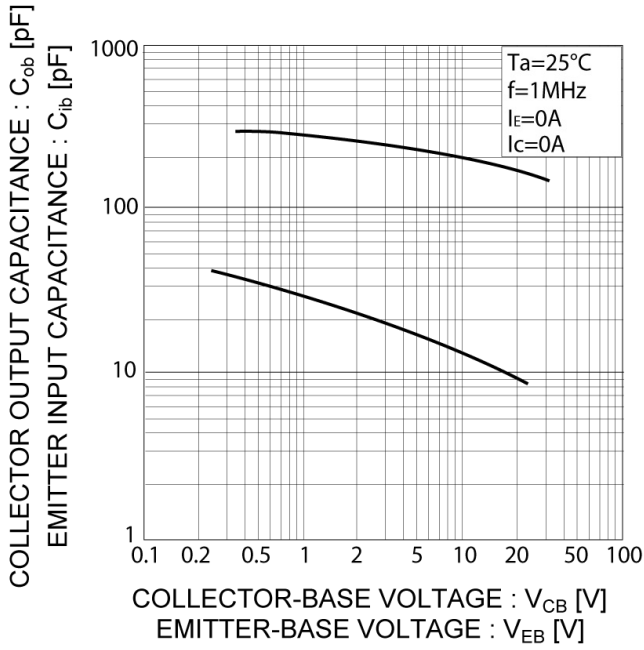
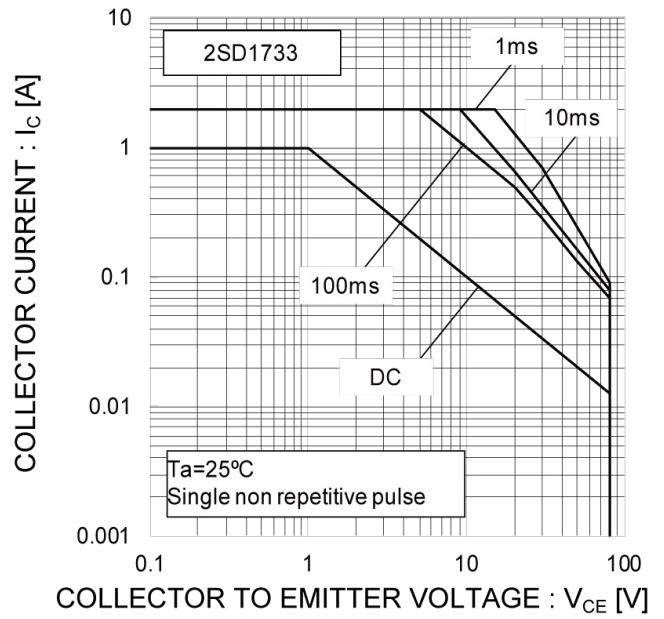
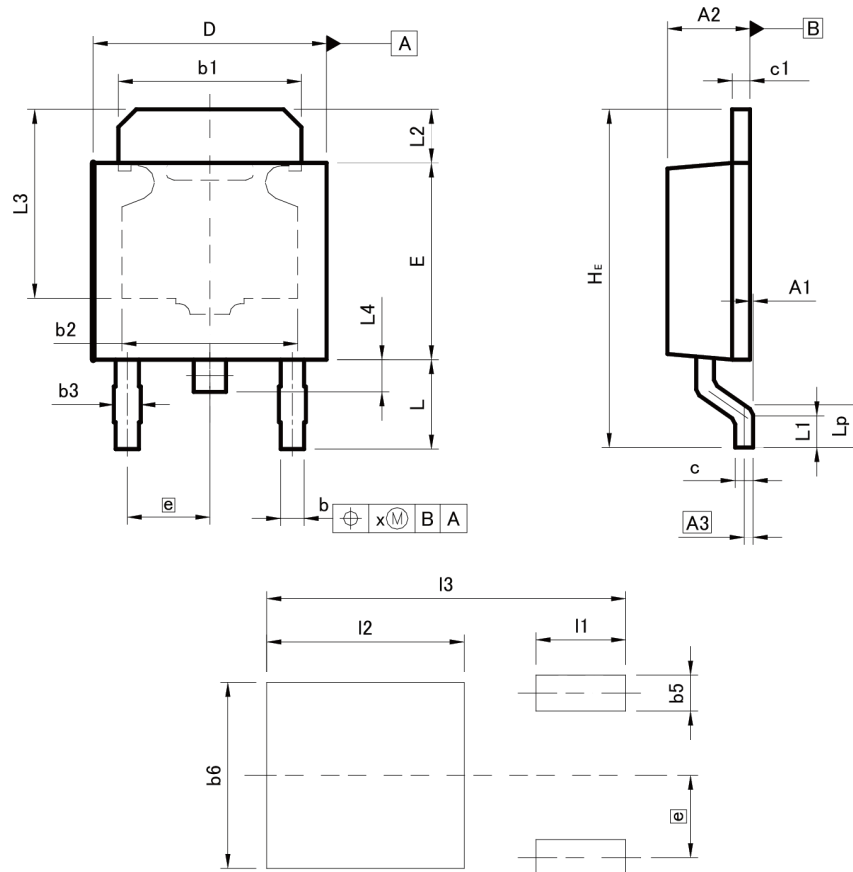


Fig.10 Safe Operating Area



●Dimensions

CPT



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

| DIM | MILIMETERS | | INCHES | |
|-----|------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A1 | 0.00 | 0.15 | 0.000 | 0.006 |
| A2 | 2.20 | 2.50 | 0.087 | 0.098 |
| A3 | 0.25 | | 0.010 | |
| b | 0.55 | 0.75 | 0.022 | 0.030 |
| b1 | 5.00 | 5.30 | 0.197 | 0.209 |
| b2 | 5.00 | | 0.197 | |
| b3 | 0.75 | | 0.030 | |
| c | 0.40 | 0.60 | 0.016 | 0.024 |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 |
| D | 6.30 | 6.70 | 0.248 | 0.264 |
| E | 5.40 | 5.80 | 0.213 | 0.228 |
| e | 2.30 | | 0.091 | |
| HE | 9.00 | 10.00 | 0.354 | 0.394 |
| L | 2.20 | 2.80 | 0.087 | 0.110 |
| L1 | 0.80 | 1.40 | 0.031 | 0.055 |
| L2 | 1.20 | 1.80 | 0.047 | 0.071 |
| L3 | 5.30 | | 0.209 | |
| L4 | 0.90 | | 0.035 | |
| Lp | 1.00 | 1.60 | 0.039 | 0.063 |
| x | - | 0.25 | - | 0.010 |

| DIM | MILIMETERS | | INCHES | |
|-----|------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| b5 | - | 1.00 | - | 0.04 |
| b6 | - | 5.20 | - | 0.205 |
| l1 | - | 2.50 | - | 0.098 |
| l2 | - | 5.50 | - | 0.217 |
| l3 | - | 10.00 | - | 0.394 |

Dimension in mm/inches

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